Luminescence of Europium(III) and Manganese(II) in **Barium and Zinc Orthosilicate**

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The aim of this work is to report on the luminescence properties of BaZnSiO₄ activated by Eu³⁺ and Mn²⁺ ions. Doped and undoped powder samples were prepared by solid-state reaction starting from oxides and carbonates or Ba₂SiO₄:Èu³⁺ and Zn₂SiO₄:Mn²⁺ precursors. X-ray diffraction powder data, IR vibrational, and UV-vis luminescence spectroscopies were carried out. Results showed that doped and undoped samples from both types of precursors have the same structure and crystallize with a superstructure of hexagonal kalsilite. Vibrational spectroscopy has confirmed the formation of a silicate group, which outlines differences between products and silicate precursors. The observed luminescence assigned to Eu³⁺ and Mn²⁺ transitions covered most parts of the visible spectrum, an important requirement for phosphors in fluorescent low-pressure mercury vapor lamps.

Introduction

Phosphors or luminescent materials are widely used to generate visible light, mainly in a fluorescent lamp field. There are two kinds of fluorescent lamps to generate white light: high- and low-pressure mercury vapor lamps. 1 Basically, both lamps require phosphors that absorb UV radiation and emit an appropriate color set that results in white emission. Among the host lattices for luminescent materials, specially the ones used in lamps,2 silicate compounds have been extensively investigated^{3–8} because of their stability, visible light transparency, and relative easy preparation. For instance, zinc orthosilicate (willemite, Zn₂SiO₄, trigonal crystalline system, $\bar{R}3$ space group³) doped with divalent manganese ions is commercially used as a green phosphor, which has been studied by various experimental techniques since the 1930s.⁴ Other luminescent colors can be achieved by using Eu²⁺ in Ba₂SiO₄,⁵ $(Ca,Sr)_2MgSi_2O_7$, $MSiO_3$ (M = Ba, Sr, Ca), $BaSi_2O_5$, BaMgSiO₄, CaMgSiO₄, and Sr₂LiSiO₄F.⁶ Recently, the matrix Ba₂SiO₄ (orthorhombic crystal system, Pmcn space group) was doped with Eu³⁺ ion and was reported as a red phosphor presenting anomalous Eu³⁺ transitions. ⁷ Also, it was shown that Mn⁵⁺ can be stabilized in this matrix of Ba₂SiO₄.8

A tricolor lamp is a type of low-pressure vapor lamp obtained by combining three phosphors that emit light in narrow wavelength intervals centered at around 450, 550, and 610 nm.9 In this context, one host lattice that can be activated by different ions emitting in different regions of the visible spectrum is a challenge for the solid materials syntheses. It is important to find a matrix in which different activation ions can be structurally substituted for cation sites. BaZnSiO4, whose structure has already been investigated, 10-12 may incorporate different doping ions and has not been studied as a matrix for luminescent materials so far. The aim of this work is to report on luminescent properties of BaZnSiO₄ activated by Eu³⁺ and Mn²⁺ ions for application feasibility in a fluorescent lamp field.

Experimental Section

Sample Preparation. BaZnSiO₄ doped with Eu³⁺ and Mn²⁺ (both 2 at. %) and undoped powder samples were prepared by a solid-state reaction, using a tubular furnace with alumina tubes and boats at 1200 °C for 12 h under a dynamic argon atmosphere. To obtain an X-ray powder data pattern,

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the undoped BaZnSiO₄ sample was heated twice, resulting in 36 h of total heating time. The starting materials used for the undoped powder were Ba₂SiO₄ and Zn₂SiO₄, independently prepared from BaCO₃ (Merck), ZnO (Baker & Adams), and SiO₂ (Merck, 60 HR), all grade reagents, at 1200 °C for 4 h in an argon dynamic flow. Oxygen, water vapor, and carbon dioxide impurities were avoided during dynamic argon flow by using an adequate purifying system. The doped samples were obtained by two methods: Method 1 (M1)-starting from previously obtained doped orthosilicates (Ba₂SiO₄:Eu³⁺ Žn₂SiO₄:Mn²⁺). Method 2 (M2)—using a stoichiometric mixture containing the oxides and carbonate and the activators, Eu₂O₃ (Aldrich, 99.99%) and MnCO₃ (Riedel), homogenized by grinding the powders in mortar agate. The experimental conditions (time, temperature, and atmosphere) in both methods and in the undoped compound preparation were the same. The doped sample prepared by method 1, M1, was annealed as well as the other sample prepared by method 2, M2, resulting in 24 h of total heating time.

Sample Characterization. In all cases, the structure of the powders was checked by X-ray powder diffraction using a Siemens D5000 diffractometer ($\Delta 2\theta = 4^{\circ} - 70^{\circ}$, 0.2° increments, integration time = 3 s, Cu K α_1 radiation, $\lambda = 1.540598$ Å, and secondary graphite monochromator). The compounds were also checked by IR vibrational absorption spectroscopy (infrared spectrophotometer Nicolet, model FT-IR 730). Excitation and emission spectra were recorded using a Fluorolog SPEX F212I spectrofluorimeter equipped with a 450-W xenon lamp as the light source and Hamamatsu R928 photomultiplier. Lifetime measurements were carried out with a 1934 phosphorimeter coupled with the spectrofluorimeter and equipped with a pulsed xenon lamp EG&GFX-265.

Results and Discussion

1. X-ray Diffraction Powder Data. X-ray diffractograms obtained for all samples are represented in Figure 1. The undoped sample X-ray diffractogram was also analyzed using Rietveld refinements performed by the DBWS-9411¹³ program to compare with literature results. The unit-cell parameters calculated as well as literature values reported by different references and summarized in the next paragraph are listed in Table 1.

Initially, Ba-substituted BaAl₂O₄ compounds, BaZn-GeO₄, BaMgSiO₄, and BaZnSiO₄, were reported by Do Dinh and Durif¹⁰ as crystallizing with small hexagonal unit cells, suggesting that they were isostructural with kalsilite (KAlSiO₄). Diffraction powder data about the BaZnSiO₄ structure were reported in JCPDS-International Centre for Diffraction¹¹ in agreement with Do Dinh and Durif. 10 However, other studies established the existence of a $(2 \times A, C)$ superstructure for BaAl₂O₄¹⁴ and a temperature-dependent ($\sqrt{3} \times A$, $4 \times C$) superstructure for BaZnGeO₄. 15-17 BaMgSiO₄ and BaZnSiO₄ compounds were also reinvestigated using powder X-ray and neutron diffractions, and the discovering of a new isostructural compound, BaCoSiO4, was reported by Liu and Barbier. 12 Those authors refined the crystal structures of BaMSiO₄ (M = Co, Mg, and Zn) compounds and showed that they are isostructural Ba-stuffed derivatives of tridymite (SiO₂) and crystallize with a

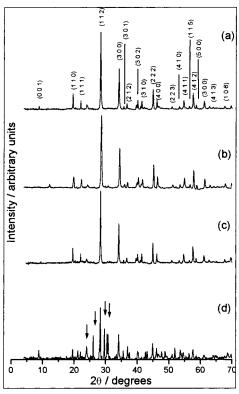


Figure 1. Powder X-ray diffractogram of (a) BaZnSiO₄ undoped sample obtained after solid state reaction under 1200 °C for 36 total heating hours. (b) BaZnSiO₄:Eu³+,Mn²+ sample obtained from a mixture containing the oxides and carbonates (M2) with 12 total heating hours. (c) BaZnSiO₄:Eu³+,Mn²+ sample obtained from a mixture containing the oxides and carbonates (M2) with 24 total heating hours. (d) BaZnSiO₄:Eu³+,Mn²+ sample obtained from Ba₂SiO₄:Eu³+ and Zn₂SiO₄:Mn²+ (M1) with 12 total heating hours. The hkl reflections were assigned according to mathematical simulation using unit-cell parameters from ref 12.

Table 1. Hexagonal Unit-Cell Parameters (Å) and Volumes (ų) for BaZnSiO₄

BaZnSiO ₄	a	c	V	space group
ref 10	5.244(3)	8.735(5)	104.0	$P6_{3}22$
ref 11	5.2518(3)	8.729(1)	208.50	$P6_{3}22$
ref 12	9.0955(5)	8.7251(9)	625.11(7)	$P6_3$
undoped sample (36 h)	9.1005	8.7314	626.36	

 $(\sqrt{3} \times A, C)$ superstructure of hexagonal (A, C) kalsilite (KAlSiO₄). The structure refinements reported allowed the determination of the atomic positions and the $P6_3$ space group for the isostructural subcell of the BaZnGeO₄ compound. Three Ba atoms positioned on the 2a and 2b sites and the Si, O, Mg, or Zn atoms occupying three sets of general 6c sites were identified. Two Ba sites presented a coordination number, CN, of 9 (2a and 2b sites), the third had a CN of 6 (2b site), and the Zn site had a CN of 4.

The unit-cell parameters listed in Table 1 show that there is good agreement between the literature and the prepared $BaZnSiO_4$ undoped sample (36 h total heating time) values, suggesting that the method starting from the silicates is successfully applied here. In the literature, the preparation of $BaZnSiO_4$ was carried out by high-temperature sintering at 1300 °C for about 48–72 h of a mixture containing $Ba(CH_3COO)_2$, ZnO, and silica gel. 12 The purpose in this work of using silicates

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Table 2. Ionic Radii Difference Percentage between Matrix and Doping Ionsa

			differen	ion-oxygen		
compd	dopant	radii/pm (CN) ¹⁹	Ba1 166(10)	Ba2 161(9)	Si 40(4)	average distance/pn
Ba ₂ SiO ₄	Eu ²⁺	149(10)	10.2			
~ .	$\mathrm{Eu^{2+}}$	144(9)		10.6	-260	
	Eu^{3+}	126(9)	24.1	21.7		
	$\mathrm{Eu^{3+}}$	121(8)	27.3	25.1		Ba1-O 298.3
	Mn^{2+}	110(8)	33.7	31.7		
	Mn^{2+}	80(4hs)			-100	Ba2-O 282.4
	Mn^{3+}	78.5(6hs)	52.7	51.2		
	Mn^{3+}	72.0(5)			-80	Si-O 163.2
	$\mathrm{Mn^{4+}}$	67.0(6)	59.6	58.4		
	$\mathrm{Mn^{4+}}$	53.0(4)			-32.5	
	$\mathrm{Mn^{5+}}$	47.0(5)	71.7	70.8		
	$\mathrm{Mn^{5+}}$	47.0(4)			-17.5	
	Mn^{6+}	39.5(4)	72.2	75.5	-1.25	
	Mn^{7+}	39.0(4)	76.5	75.8	-2.50	

compd	dopant	radii/pm (CN) ¹⁹	difference % between ionic radii Zn 74(4)	ion-oxygen average distance/pm
Zn ₂ SiO ₄				Zn1-O 194.95
	$\mathrm{Eu^{2+}}$	131(6)	-77.0	Zn2-O 196.13
	$\mathrm{Eu^{3+}}$	109 (6)	-46.9	Si-O 163.45
	Mn^{2+}	80.0(4hs)	-8.11	O-O 266.83 (tetr.Si)
	Mn^{3+}	72.0(5)	2.70	O-O 317.93(tetr.Zn1)
	$\mathrm{Mn^{4+}}$	53(4)	28.38	O-O 319.98(tetr.Zn2)
	$\mathrm{Mn^{5+}}$	47.0(4)	36.49	Si-Zn(1) 311.2
	Mn^{6+}	39.5(4)	53.38	Si-Zn(2) 309.4
	Mn^{7+}	39.0(4)	47.30	Zn1-Zn2 311.2

			differenc	ion-oxygen		
compd	dopant	radii/pm (CN) ¹⁹	Ba1&2 61(9)	Ba3 149(6)	Zn 74(4)	average distance/pm
BaZnSiO ₄	Eu ²⁺	144(9)	10.6		-94.6	
•	Eu^{2+}	131(6)		12.08	-77.0	
	$\mathrm{Eu^{3+}}$	126(9)	21.74		-70.3	Ba1-O 288.0
	$\mathrm{Eu^{3+}}$	109(6)		27.05	-46.9	
	$\mathrm{Mn^{2+}}$	110(8)	31.67			Ba[2]-O 294.0
	Mn^{2+}	81.0(6ls)		45.64		. ,
	$\mathrm{Mn^{2+}}$	97.0(6hs)		34.9		Ba[3]-O 272.0
	$\mathrm{Mn^{2+}}$	80.0(4hs)			-8.11	. ,
	Mn^{3+}	72.0(6ls)		51.68	2.70	Si-O 163.0
	Mn^{3+}	78.5(6hs)		47.31		
	$\mathrm{Mn^{4+}}$	53.0(4)		64.4	28.3	Zn-O 192
	$\mathrm{Mn^{4+}}$	67.0(6)		55.0		
	$ m Mn^{5+}$	47.0(5)		68.5	36.5	
	Mn^{6+}	39.5(4)		73.5	46.6	
	Mn^{7+}	39.0(4)		73.8	47.3	

^a CN = coordination number; hs = high spin; ls = low spin.

as precursors is to supply already formed silica tetrahedrons during their reaction to decrease time and temperature reaction. On the basis of the structure of $BaCoSiO_4$ reported by Liu and Barbier, 12 the structure of $BaZnSiO_4$ viewed along the c axis is represented in Figure 2. The Zn and Si atoms are fully ordered, with large ZnO_4 tetrahedra pointing up and small SiO_4 tetrahedra pointing down.

The doped sample prepared by the same method used for the undoped one (referred to as method 1 or M1), with 12 h of total heating time, presents a BaZnSiO₄ X-ray pattern, Figure 1d, with low intensity and many extra lines. Some of them are pointed out in Figure 1 and are assigned to Ba₂SiO₄ (3.01, 3.41, and 2.93 Å^{18a}) and BaCO₃ (3.72 Å^{18b}). In addition, this doped sample obtained by M1 has melted during the annealing. Therefore, the reaction from the doped silicates is not

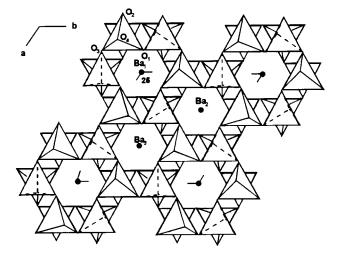


Figure 2. Structure of BaZnSiO₄ viewed along the c axis adapted from the structure of BaCoSiO₄ reported by Liu and Barbier. 12

complete and the remaining low quantities of different components probably act as melting agents.

The BaZnSiO₄ doped sample prepared by method 2 (M2), even before the annealing, presents a X-ray

⁽¹⁸⁾ Powder Diffraction File PDF-2 database sets 1–44. Pennsylvannia Joint Committee on Powder Diffraction Standards—International Center for Diffraction Data. c 1988, PDG number (a) 26-1403 and (b) 44-1487. (CD-ROM).

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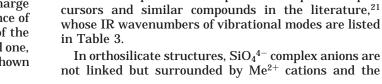
Table 3. IR Wavenumbers (cm⁻¹) of Vibrational Modes Observed in the Spectra Presented in Figure 3 and Reported for Some Compounds in the Literature^{21–23}

			Some Com	pound	is in the	Literature	-1 -0			
	SiO ₄ ⁴⁻ mode ^a						${ m CO_3^{2-}\ modes^a}$			
	A_1 S (ν_1)	F ₂ s (v ₃)	F ե (۷)	Ε b (ν ₂)	CO ₂ b (v ₃)	CO ₂ sym. s (ν_1)	CO s (ν ₂)	CO ₂ asym. s (ν_4)	ref
MgCaSiO ₄ Sr ₂ SiO ₄ Ba ₂ SiO ₄ Ba ₂ SiO ₄ Zn ₂ SiO ₄ BaZnSiO ₄	829 840 824 815	995, 965, 950, 8 980, 964, 908, 8 930, 903, 885 976, 905, 847 977, 934, 901, 8 916, 862	528, 510, 510,	507 492 488 578	483 460 406	1448				ref 21 ref 21 ref 21 Figure 3 Figure 3 Figure 3
BaCO ₃ BaCO ₃			,			1420 1448	1056	857 855	692 690	ref 22 Figure 3
					SiO ₂ mo	odes				
						E				
	E	A_2	E		E	s b		E	E	
	s ∆RSi−C	s ΔRSi-O	$_{\Delta ext{RSi-O}}^{ ext{s}}$	ΔR	s Si-O	ΔR Si-O Δα O-Si-O	Ο ΔαΟ	b -Si-O	b ΔαΟ-Si-O	ref 23
α-crystobalite SiO ₂	1200	1140	1105 1095		798 794	620 617		190 188	380 381	ref 23 Figure
					lattice ration				ref	
	ZnO			528,	495, 442				Figure 3	

^a s, stretching; b, bending.

diffraction pattern, Figure 1b,c, in good agreement with the undoped one, Figure 1a, indicating that it has the same structure represented in Figure 2. Thus, it seems that M2 is more useful than M1 to prepare doped BaZnSiO₄. Besides, because the doped samples peak positions are similar to the undoped ones, it is clear that the Eu³⁺ and Mn²⁺ doping ions do not change the general structure. Maintenance of the structure is assumed on the basis of the calculations of the percentage difference between activators and matrix ion radii in the analyzed compounds (Table 2). An acceptable percentage difference in ion radius between doping and substituting ion must not exceed 30%. Data included in Table 2 suggest that in the case of BaZnSiO₄ there is a high probability of $Eu^{3+}\, replacing\, Ba^{2+}\, despite their$ charge difference, and Mn²⁺ probably substitutes for Zn²⁺ ions. Neither activator ion is expected to occupy Si⁴⁺ sites. The following explains the charge balance upon substitution of Ba²⁺ by Eu³⁺. In M2, zinc oxide used as a precursor can lose oxygen during heating. In $Zn_{1+x}O$, a nonstoichiometric system, the metal ion is easily reduced, mainly when x is very small, $\approx 10^{-5}$, or at high temperatures where the formation of defects is favored through entropy considerations.²⁰ Charge balance requires zinc atoms reduction to Zn⁺ or Zn⁰. These reduced species formed during M2 can stabilize the Ba²⁺-Eu³⁺ system. On the other hand, in M1, the precursor zinc orthosilicate doped with manganese probably does not provide Zn reduced species to charge compensate Eu³⁺ substituted for Ba²⁺. This absence of balance can result in a less organized structure of the doped compound when compared with the undoped one, justifying the lower quality diffractogram pattern shown in Figure 1d.

2. IR Spectroscopy. Figure 3 shows the IR spectra of undoped precursors and a $BaZnSiO_4$ representative





<sup>Soc. 1958, 3137.
(23) Ocaña, M.; Fornes, V.; Garcia Ramos, J. V.; Serna, C. J. Phys. Chem. Miner. 1987, 14, 527.</sup>

ŞiO₂ (1200°C - 12 h)

Figure 3. IR vibrational absorption spectra of BaZnSiO₄ precursors and a representative sample of this compound.

sample. Silica and barium carbonate standard precur-

sors were heated in the specified conditions (see Figure

3) to supply crystalline samples. No specific literature

data were found for BaZnSiO₄ IR spectra. To assign the

observed vibrational modes, the BaZnSiO4 spectra of

different samples were compared with spectra of pre-

BaCO₃ (700°C - 4 h)

ZnO

Ba₂SiO₄ (1200°C - 8 h)

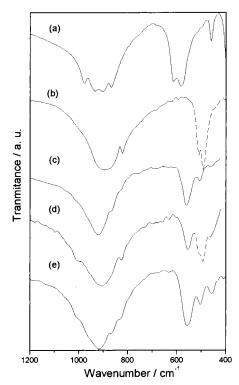
BaZnSiO₄ (1200°C - 8 h)

BaZnSiO₄ (1200°C - 36 h)

BaZnSiO₄ (1200°C - 36 h)

Wavenumber / cm

⁽²⁰⁾ Weller, M. T. *Inorganic Materials Chemistry*; Oxford Science Publications: Oxford, 1994.



4. IR vibrational absorption spectra (a) Zn₂SiO₄:Mn²⁺, (b) Ba₂SiO₄:Eu³⁺, (c) BaZnSiO₄ undoped sample obtained after solid state reaction under 1200 °C for 36 total heating hours, (d) BaZnSiO₄:Eu³⁺,Mn²⁺ sample obtained by M1 with 12 total heating hours, and (e) BaZnSiO₄:Eu³⁺,Mn²⁺ sample obtained by M2 with 24 total heating hours.

chemical bond distance between Si and O is shorter than the distance between Me and O. Therefore, internal modes for [SiO₄] are almost independent of external vibrations. In orthosilicate structures [SiO₄] internal modes are split because of their site symmetry (crystal field splitting) and unit-cell space symmetry (Davydov's splitting). Davydov's splitting depends on the anioncation mixed vibrations whereas crystal field splitting depends on anion internal force field change.²¹

First, in Figure 3, some differences are observed between wavenumber positions of the standard precursors and all silicates. The vibrational modes attributed to Si-O stretching (ν_3 , in Table 3) in the silicate are shifted to smaller wavenumbers compared with silica, indicating the formation of SiO₄⁴⁻. Second, the features and the splits present in the spectra of Ba₂SiO₄ and Zn₂SiO₄ related to SiO₄⁴⁻ modes are completely different. In addition, the BaZnSiO4 spectrum has its own identity. It can also be noted throughout Table 3 that the wavenumber positions related to BaZnSiO₄ (hexagonal structure) and MgCaSiO₄ (orthorhombic structure) SiO₄⁴⁻ modes are also different, exemplifying the sensibility of the technique in relation to the structure of the system. Finally, vibrational spectroscopy confirms the formation of silicate groups, which exhibits differences among the prepared silicates identified.

The sensitivity of the IR technique to a short distance structure of the systems makes possible a comparison of M1 and M2 (to prepare BaZnSiO4 doped samples). The 1200-400-cm⁻¹ IR spectra of doped silicate precursors compared with those of undoped BaZnSiO₄ (36 h of total heating time) are shown in Figure 4. The large

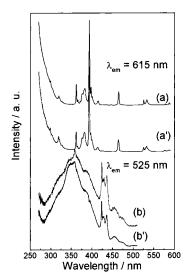


Figure 5. Excitation spectra at room temperature of BaZnSiO₄:Eu³⁺,Mn²⁺ obtained by M1 under 12 h of total heating (a,b) and by M2 under 24 h of total heating (a', b'). The emission wavelength fixed was 615 nm in (a) and (a') and 525 nm in (b) and (b').

band at $1000-730~\text{cm}^{-1}$, assigned to the $\nu_3(\text{SiO}_4)$ mode in Table 3, is the same for doped (Figure 4d,e) and undoped (Figure 4c) BaZnSiO₄ samples. On the other hand, the split band ranging from 535 to 418 cm⁻¹ (dashed line) assigned to the $v_4(SiO_4)$ mode is observed in both Ba₂SiO₄:Eu³⁺ and doped BaZnSiO₄ prepared by M1 (Figure 4b,d). This fact supports the conclusion based on X-ray diffraction that barium orthosilicate is also formed by M1.

3. UV-Vis Luminescence Spectroscopy. The excitation and emission spectra at room temperature of BaZnSiO₄:Eu³⁺,Mn²⁺ samples prepared by M1 and M2 are represented in Figures 5 and 6, respectively. In both cases, it is possible to observe the different optical transitions that are related to each activator depending on the wavelength chosen. The excitation spectra measured fixing the highest intensity of ${}^5D_0 \rightarrow {}^7F_2$ Eu³⁺ relaxation transition (615 nm) in Figure 5a,a' show the group of Eu³⁺ excitation transitions assigned to ${}^{7}F_{0} \rightarrow$ ${}^{5}\!L_{6}, {}^{5}\!D_{3}$. The corresponding emission spectra using the 393 nm excitation ${}^{\bar{7}}F \rightarrow {}^5L_6$ transition, shown in Figure 6a,a', is a set of relaxation transitions $^5D_0 \rightarrow {}^7F_{0,1,2,3,4}$ in the red region attributed to the Eu³⁺ in low-symmetry sites.²⁴ On the other hand, the excitation spectra represented in Figure 5b,b' show the set of transitions of tetrahedral Mn²⁺ ion, ${}^{6}A_{1} \rightarrow {}^{4}T_{1}$, ${}^{6}A_{1} \rightarrow {}^{4}T_{2}$, ${}^{6}A_{1} \rightarrow {}^{4}E$ ${}^{4}A_{1}$, ${}^{4}G$), ${}^{6}A_{1} \rightarrow {}^{4}T_{2}$, and ${}^{6}A_{1} \rightarrow {}^{4}E$ (${}^{4}D$), 25 and in the emission spectra, Figure 6b,b', a green broad band attributed to the ${}^4T_1 \rightarrow {}^6A_1$ Mn²⁺ transition is mainly observed. The weak emission line observed at the lower energy side in Figure 6b,b' at 615 nm is assigned to ⁵D₀ \rightarrow $^{7}F_{2}$ Eu $^{3+}$ transition. The appearance of this Eu $^{3+}$ emission is likely to support the belief that there is energy transfer from Mn²⁺ to Eu³⁺ because the 422 nm excitation wavelength is only observed in the Mn²⁺ excitation spectra, ${}^{6}A_{1} \rightarrow {}^{4}E, {}^{4}A_{1}({}^{4}G)$ transition. Finally, Figure 6c,c' shows that when the excitation wavelength

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Elsevier: New York, 1984.

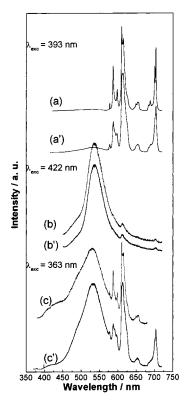


Figure 6. Emission spectra at room temperature of BaZnSiO₄:Eu³⁺,Mn²⁺ obtained by method 1 under 24 h of total heating (a,b,c) and by method 2 under 12 h of total heating (a',b',c'). The excitation wavelength fixed was 393 nm in (a) and (a'), 422 nm in (b) and (b'), and 363 nm in (c) and (c').

363 nm is used, it is possible to observe both Eu^{3+} and Mn^{2+} transitions recovering most of the visible spectrum due to simultaneous excitation of Eu^{3+} and Mn^{2+} ions.

On the basis of the results concerning room-temperature spectra of the doped samples, it seems that, despite the differences in XRD and IR data, the doped BaZnSiO₄ samples obtained by methods M1 and M2 have almost the same optical excitation and emission behavior. Nevertheless, some measurements were carried out at low temperature (liquid N₂), monitoring the $^5D_0 \rightarrow {}^7F_0 \ Eu^{3+} \ transition in each doped BaZnSiO_4$ sample, and some different features are observed (see Figure 7). Considering that in the BaZnSiO₄ structure there are three different low-symmetry barium sites on which Eu^{3+} can substitute, the ${}^5D_0 \rightarrow {}^7F_0$ transition can consist of one more line. Therefore, BaZnSiO₄:Eu³⁺,-Mn²⁺ prepared by M1 (Figure 7a) shows two lines centered on 577.6 and on 579.2 nm, one stronger and straighter and the other weaker and broader, respectively. BaZnSiO₄:Eu³⁺,Mn²⁺ prepared by M2, on the other hand, exhibits just one broad line with a maximum at 577.6 nm (Figure 7b). Two of the Ba²⁺ sites in the BaZnSiO₄ host lattice have a CN of 9, but with different site symmetry (2a and 2b), so they are slightly different and cannot strongly modify the values of 5D0 or 7F_0 levels. The third Ba^{2+} site with a CN of 6 and site symmetry 2b should result in a different position of the ${}^5D_0 \rightarrow {}^7F_0$ transition and must have low occupation probability. Then, in BaZnSiO₄:Eu³⁺,Mn²⁺ prepared by M2, the broad line observed can be resolved into at least two Lorentzian curves (dashed lines in Figure 7b), one weaker with a maximum at 576.6 and another stronger at \approx 577.7 nm. The strongest line at 577.7 can

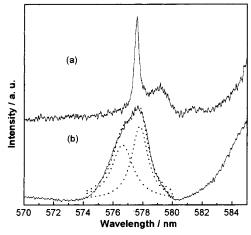


Figure 7. Emission spectra in the region of ${}^5D_0 \rightarrow {}^7F_0$ Eu $^{3+}$ transition at N_2 liquid temperature of BaZnSiO $_4$:Eu $^{3+}$,Mn $^{2+}$ obtained by method 1 under 12 h of total heating (a) and by method 2 under 24 h of total heating (b). The excitation wavelength fixed was 393 nm in both cases.

be assigned to Eu^{3+} in the Ba^{2+} site with a CN of 9 and the other to Eu^{3+} in the Ba^{2+} site with a CN of 6. In the case of $BaZnSiO_4$: Eu^{3+} , Mn^{2+} prepared by M1 where the Ba_2SiO_4 phase is detected by XRD and IR, Eu^{3+} can also substitute for Ba^{2+} in this compound, which explains the shifted broad weak line presented in the emission spectra at 579.2 nm (Figure 7a). The other line, at 577.6 nm, is located at the same position as that for the sample prepared by M2 and can have analogous assignment on Eu^{3+} in the Ba^{2+} site with a CN of 9. The Ba^{2+} site with a CN of 6 probably does not have a large occupation.

In our discussion of the X-ray diffraction data it is proposed that the Zn⁺ species can charge compensate Eu³⁺ substituted for Ba²⁺. Spectroscopy studies of the Ba₂SiO₄:Eu³⁺ compound was reported⁷ and the evidence of Eu³⁺-O²⁻ associates in this system as a result of a charge-compensating mechanism was established. This Eu^{3+} – O^{2-} associates presented a 5D_0 \rightarrow 7F_0 Eu^{3+} transition and charge-transfer band at the unusual positions of 572 and 340 nm, respectively, while the Eu³⁺ in Ba²⁺ sites showed a ${}^5D_0 \rightarrow {}^7F_0$ Eu^{3+*} transition at a standard position of 581 nm. Therefore, a charge compensation mechanism can also be inferred in the BaZnSiO₄:Eu³⁺,-Mn²⁺ system by assuming the formation of Eu³⁺-O²⁻ associates. Extra spectroscopic measurements were also performed for all BaZnSiO₄:Eu³⁺,Mn²⁺ systems by fixing appropriate wavelengths to identify the presence of Eu³⁺-O²⁻ associates. But no evidence is found in the excitation and emission spectra measured, indicating that in BaZnSiO₄:Eu³⁺,Mn²⁺ systems Eu³⁺-O²⁻ associates are not formed. These results support the hypothesis that charge is compensated by Zn⁺ species.

Lifetime measurements were carried out by monitoring Eu^{3+} and Mn^{2+} transitions in the silicate precursors as well as in the barium and zinc orthosilicate systems prepared by M1 and M2. These results are summarized in Table 4. A significant decrease of the lifetime for the Mn^{2+} ion radiative level transition in M1 and M2 barium and zinc orthosilicates is observed when compared to that of the zinc orthosilicate precursor. This lifetime decrease, approximately to half the value, is probably related to energy transfer mechanisms between Mn^{2+} and Eu^{3+} discussed above.

Table 4. Lifetime Values of Doped Compounds

	λ positi	on/nm	ion		
compound	excitation	emission	monitored	$\tau/{ m ms}$	
BaZnSiO ₄ :Eu ³⁺ ,Mn ²⁺ (M1)	393	615	Eu ³⁺	1.94	
	424	536	Mn^{2+}	4.50	
$BaZnSiO_4:Eu^{3+},Mn^{2+}$ (M2)	394	615	Eu^{3+}	1.78	
	424	530	Mn^{2+}	4.52	
Ba ₂ SiO ₄ :Eu ³⁺	394	612	$\mathrm{Eu^{3+}}$	1.98	
Zn ₂ SiO ₄ :Mn ²⁺	422	525	Mn^{2+}	10.2	

Table 5. C.I.E. Chromaticity Coordinate, xy

		aticity inates		
compound	X	У	$\lambda_{exc}\!/\!nm$	ref
BaZnSiO ₄ :Eu ³⁺ ,Mn ²⁺ (M2)	0.348	0.474	363	this work
Ba ₂ SiO ₄ :Eu ³⁺	0.234	0.248	340	this work
Zn ₂ SiO ₄ :Mn ²⁺	0.243	0.693	365	this work
$Zn_2SiO_4:Mn^{2+}$	0.252	0.691		ref 2
400-W HPMV Lamp	0.311	0.391		ref 2

To evaluate the material performance on color luminescent emission, C.I.E., chromaticity coordinates xy were obtained from calculations based on the emission spectra. The data are summarized in Table 5. Only BaZnSiO₄:Eu³⁺,Mn²⁺ (M2) was chosen to be investigated due to the fact that this sample presents the best structural and optical characteristics. The C.I.E. calculated values for precursors Ba₂SiO₄:Eu³⁺ Zn₂SiO₄:Mn²⁺ and some values reported in the literature³ for Zn₂SiO₄:Mn²⁺ and a 400-W HPMV lamp are also included. The silicate doped with both Eu³⁺ and Mn²⁺ presents xy C.I.E. chromaticity coordinates related to the emission color with green and red components, resulting in a color emission close to white.

Conclusions

The present paper reported on BaZnSiO4 activated by Eu³⁺ and Mn²⁺ studies, where Eu³⁺ substitutes for Ba²⁺ and Mn²⁺ substitutes for Zn²⁺ ions. X-ray and IR results indicate that the BaZnSiO₄ undoped sample is successfully obtained using the method started from Ba₂SiO₄ and Zn₂SiO₄ independently prepared. On the other hand, doped BaZnSiO₄ started from the mixture containing the oxides, carbonates, and the activators presents a larger purity phase. Zinc oxide precursors appear to help charge compensation by the formation of reduced species.

Luminescence studies on doped samples resulted in the observation of different optical transitions that are related to each activator in the BaZnSiO₄ matrix. Energy transfer from Mn²⁺ to Eu³⁺ ions is also observed. When the excitation wavelength 363 nm is used, both Eu³⁺ and Mn²⁺ transitions covering most of the part of the visible spectrum are detected. Because in fluorescent high-pressure mercury vapor lamps the radiation originated by the mercury ion is 366 nm, it is possible to suggest that BaZnSiO₄:Eu³⁺,Mn²⁺ has some adequate luminescent features that suggest its use as a lamp applied material.

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